

2. The voltage gain between the gate and the drain of a MOSFET amplifier is -27 V/V , the NMOS transistor capacitors $C_{gs}=0.3 \text{ pF}$ and $C_{gd}=0.1 \text{ pF}$. For what range of signal-resistance can you expect the 3-dB frequency to exceed 10 MHz , neglect the effect of R_G .

$$f_H = \frac{1}{2\pi [C_{gs} + C_{gd}(1+27)] \times R_{sig}} > 10 \text{ M}$$

$$= \frac{1}{2\pi [3.1 \text{ p} \times R_{sig}]} > 10 \text{ M}$$

$$R_{sig} < \frac{1}{2\pi \times 3.1 \text{ p} \times 10 \text{ M}}$$

$$R_{sig} < 5.13 \text{ K}\Omega$$